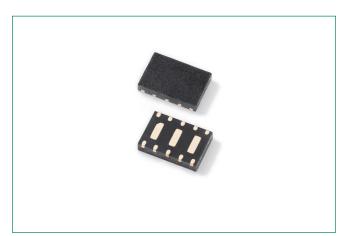
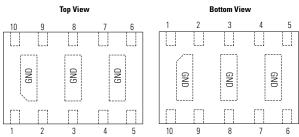
# **SP2574NUTG** 2.5V 40A Diode Array

### OBSOLETE DATE: 12/31/2020 PCN/ECN# ESU270-49 REPLACED BY: SP2555NUTG or AQ2555NUTG



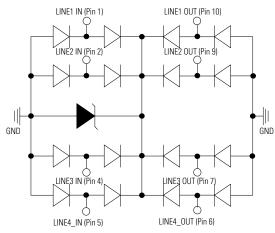


## Pinout



Note: PIN3, PIN8 are same potential with GND

## **Functional Block Diagram**



## Description

The SP2574NUTG is a low-capacitance, TVS Diode Array designed to provide protection against ESD (electrostatic discharge), CDE (cable discharge events), EFT (electrical fast transients), and lightning induced surges for high-speed, differential data lines. It's packaged in a  $\mu$ DFN package (3.0 x 2.0mm) and each component can protect up 4 channels or 2 differential pairs, up to 40A (IEC 61000-4-5) and up to 30kV ESD (IEC 61000-4-2). The "flow-through" design minimizes signal distortion, reduces voltage overshoot, and provides a simplified PCB design.

The SP2574NUTG with its low capacitance and low clamping voltage makes it ideal for high-speed data interfaces such as 1GbE applications found in notebooks, switches, etc.

## **Features & Benefits**

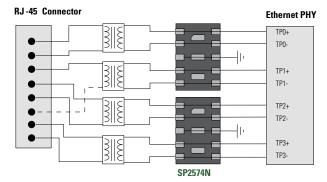
- ESD, IEC 61000-4-2, ±30kV contact, ±30kV air
- EFT, IEC 61000-4-4, 40A (5/50ns)
- Lightning, 40A (8/20µs as defined in IEC 61000-4-5 2nd Edition)
- Low capacitance of 3.8pF@0V (TYP) per I/O
- Low leakage current of 0.1µA (TYP) at 2.5V

## Applications

- 10/100/1000 Ethernet
- WAN/LAN Equipment
- Desktops, Servers and Notebooks

- µDFN-10 package is optimized for high-speed data line routing
- Provides protection for two differential data pairs (4 channels) up to 40A
- Low operating and clamping voltage
- AEC-Q101 qualified
- LVDS Interfaces
- Integrated Magnetics
- Smart TV

## **Application Example**



#### Life Support Note:

Not Intended for Use in Life Support or Life Saving Applications

The products shown herein are not designed for use in life sustaining or life saving applications unless otherwise expressly indicated.



Lighthin defined Edition) Low cap 3.8pF@

### **Absolute Maximum Ratings**

Symbol	Parameter	Value	Units
I <sub>PP</sub>	Peak Current (t <sub>p</sub> =8/20µs)	40 1	А
P <sub>Pk</sub>	Peak Pulse Power (t = 8/20µs)	1000	W
T <sub>OP</sub>	Operating Temperature	-40 to 125	C°
T <sub>STOR</sub>	Storage Temperature	-55 to 150	°C

#### Notes:

1. Rating with 2 pins connected together per sugguested diagram (For example, pin1 is connected to pin 10, pin 2 is connected to Pin 9, Pin 4 is connected to pin 7 and pin 5 is connected to pin 6)

Caution: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the component. This is a stress only rating and operation of the component at these or any other conditions above those indicated in the operational sections of this specification is not implied.

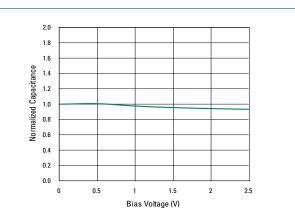
## Electrical Characteristics (T<sub>op</sub>=25°C)

Parameter	Symbol	Test Conditions	Min	Тур	Мах	Units
Reverse Standoff Voltage	V <sub>RWM</sub>	I <sub>R</sub> ≤ 1µA			2.5	V
Reverse Leakage Current	I <sub>R</sub>	$V_{RWM} = 2.5V, T = 25^{\circ}C$		0.1	0.5	μΑ
Breakdown Voltage	V <sub>BR</sub>	$I_{t1} = 1\mu A$	3.0	3.7	4.5	V
Snap Back Voltage	V <sub>SB</sub>	I <sub>H</sub> = 1mA	3.0			V
Clamp Voltage V <sub>c</sub>		I <sub>PP</sub> = 1A, t <sub>p</sub> = 8/20μs Any I/O to Ground			4.5	V
		$I_{pp} = 10A$ , $t_p = 8/20\mu s$ Any I/O to Ground			7.5	
		$I_{pp} = 25A, t_p = 8/20\mu s$ Any I/O to Ground $I_{pp} = 40A, t_p = 8/20\mu s$			12.0	
		I <sub>pp</sub> = 40A, t <sub>p</sub> = 8/20μs Line-to-Line <sup>1</sup> , two I/O Pins connected together on each line			20.0	
Dynamic Resistance <sup>2</sup>	R <sub>DYN</sub>	TLP, t <sub>p</sub> =100ns, Any I/O to Ground		0.13		Ω
CCD With stand Valtage	N/	IEC 61000-4-2 (Contact)	±30			kV
ESD Withstand Voltage V <sub>ESD</sub>	V <sub>ESD</sub>	IEC 61000-4-2 (Air)	±30			kV
Diode Capacitance	C <sub>I/O to GND</sub>	Between I/O Pins and Ground $V_{_{\rm R}}$ = 0V, f = 1MHz		3.8	5.0	pF
	C <sub>I/O to I/O</sub>	Between I/O Pins $V_R = 0V$ , f = 1MHz		1.7		pF

#### Notes:

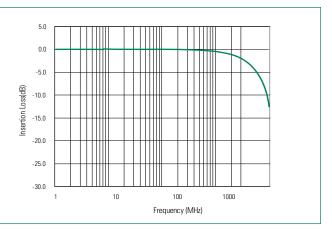
1. Rating with 2 pins connected together per sugguested diagram (For example, pin1 is connected to pin 10, pin 2 is connected to Pin 9, Pin 4 is connected to pin 7 and pin 5 is connected to pin 6)

2. Transmission Line Pulse (TLP) with 100ns width, 2ns rise time, and average window t1=70ns to t2= 90ns

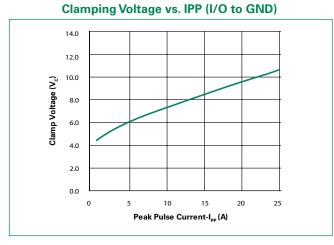


## Normalized Capacitance vs. Voltage

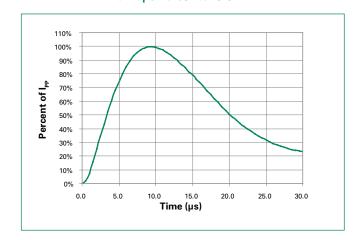
## Insertion Loss (S21)



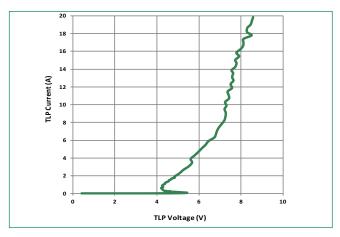




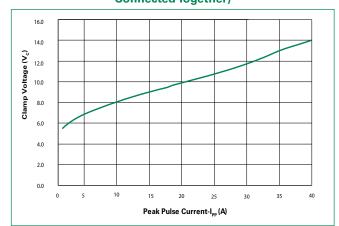
8/20µs Pulse Waveform



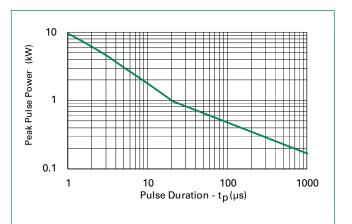
**Transmission Line Pulse (TLP)** 



Clamping Voltage vs. IPP (Line-to-Line, Two I/O Pins Connected Together)



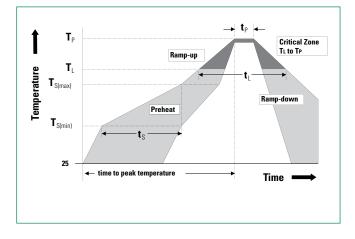
Non-Repetitive Peak Pulse Power vs. Pulse Time



## TVS Diode Array Datasheet

## **Soldering Parameters**

Reflow Condition		Pb – Free assembly	
	- Temperature Min (T <sub>s(min)</sub> )	150°C	
Pre Heat	- Temperature Max (T <sub>s(max)</sub> )	200°C	
	- Time (min to max) (t <sub>s</sub> )	60 - 180 secs	
Average ramp up rate (Liquidus) Temp $(T_L)$ to peak		3°C/second max	
T <sub>S(max)</sub> to T <sub>L</sub> - Ramp-up Rate		3°C/second max	
Reflow	- Temperature (T <sub>L</sub> ) (Liquidus)	217°C	
	- Temperature (t <sub>L</sub> )	60 – 150 seconds	
Peak Temperature (T <sub>P</sub> )		260 <sup>+0/-5</sup> °C	
Time within 5°C of actual peak Temperature $(t_p)$		20-40 seconds	
Ramp-down Rate		6°C/second max	
Time 25°C to peak Temperature (T <sub>p</sub> )		8 minutes Max.	
Do not exceed		260°C	



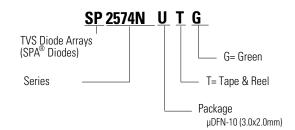
## **Product Characteristics**

Lead Plating	Pre-Plated Frame	
Lead Material	Copper Alloy	
Lead Coplanarity	0.004 inches(0.102mm)	
Substrate material	Silicon	
Body Material	Molded Compound	
Flammability	UL Recognized compound meeting flammability rating V-0	

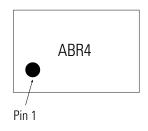
## **Ordering Information**

Part Number	Package	Min. Order Qty.
SP2574NUTG	µDFN-10 (3.0x2.0mm)	3000

## Part Numbering System

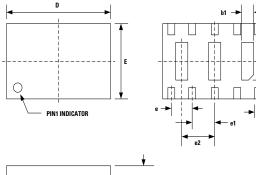


### **Part Marking System**



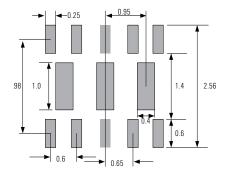
## Package Dimensions - µDFN-10 (3.0x2.0mm)

- b





Recommended Solder Pads



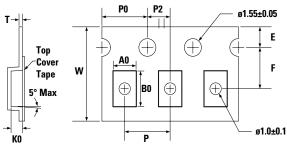
Symbol     Min     Nom     Max     Min       A     0.50     0.60     0.65     0.020     0       A1     0.00     0.03     0.05     0.000     0       A3     0.15     Ref     0.00     0.00     0	μDFN-10 (3.0x2.0mm)			
Symbol     Min     Nom     Max     Min       A     0.50     0.60     0.65     0.020     0       A1     0.00     0.03     0.05     0.000     0       A3     0.15     Ref     0.00     0.00     0	MO-229			
Min     Nom     Max     Min       A     0.50     0.60     0.65     0.020     0       A1     0.00     0.03     0.05     0.000     0       A3     0.15 Ref     0.00     0.05     0.006     0	nches			
A1     0.00     0.03     0.05     0.000     0       A3     0.15 Ref     0.00     0 </th <th>Nom</th> <th>Max</th>	Nom	Max		
A3     0.15 Ref     0.00       b     0.15     0.20     0.25     0.006     0	0.024	0.026		
<b>b</b> 0.15 0.20 0.25 0.006 0	0.001	0.002		
	06 Ref			
	800.0	0.010		
<b>b1</b> 0.25 0.35 0.45 0.010 0	0.014	0.018		
<b>D</b> 2.90 3.00 3.10 0.114 0	0.118	0.122		
<b>E</b> 1.90 2.00 2.10 0.075 (	0.079	0.083		
e 0.60 BSC 0.02	24 BSC			
e1 0.65 BSC 0.02	26 BSC			
<b>e2</b> 0.95 BSC 0	.037			
L 0.25 0.30 0.35 0.010 (	0.012	0.014		
L1 0.95 1.00 1.05 0.037 (	0.039	0.041		

Notes :

1. All dimensions are in millimeters

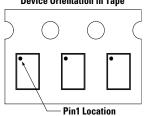
Dimensions include solder plating.
Dimensions are exclusive of mold flash & metal burr

## Tape & Reel Specification - µDFN-10 (3.0x2.0mm)



**Device Orientation in Tape** 

Package	μDFN-10 (3.0x2.0mm)	
Symbol	Millimeters	
A0	2.30 +/- 0.10	
B0	3.20 +/- 0.10	
E	1.75 +/- 0.10	
F	3.50 +/- 0.05	
КО	1.0 +/- 0.10	
Р	4.00 +/- 0.10	
P0	4.00 +/- 0.10	
P2	2.00 +/- 0.10	
т	0.3 +/- 0.05	
W	8.00 + 0.30 /- 0.10	



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